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NEWS	1			Web Page for STN Seminar Schedule - N. America
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				minutes
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NEWS	4	AUG	24	ENCOMPLIT/ENCOMPLIT2 reloaded and enhanced
NEWS	5	AUG	24	CA/CAplus enhanced with legal status information for
				U.S. patents
NEWS	6	SEP	09	50 Millionth Unique Chemical Substance Recorded in
				CAS REGISTRY
NEWS	7	SEP	11	WPIDS, WPINDEX, and WPIX now include Japanese FTERM
				thesaurus
NEWS	8	OCT	21	Derwent World Patents Index Coverage of Indian and
				Taiwanese Content Expanded
NEWS	9	OCT	21	Derwent World Patents Index enhanced with human
				translated claims for Chinese Applications and
				Utility Models
NEWS			23	Addition of SCAN format to selected STN databases
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NEWS NEWS			01	
NEWS	13	DEC	UΙ	DGENE, USGENE, and PCTGEN: new percent identity feature for sorting BLAST answer sets
NEWS	2.4	DEC	0.0	Derwent World Patent Index: Japanese FI-TERM
NEWS	14	DEC	02	thesaurus added
NEWS	1.6	DEC	02	PCTGEN enhanced with patent family and legal status
MEMO	10	DEC	02	display data from INPADOCDB
NEWS	16	DEC	02	USGENE: Enhanced coverage of bibliographic and
MEMP	10	DEC	02	sequence information
NEWS	17	DEC	21	New Indicator Identifies Multiple Basic Patent
112110		DIC		Records Containing Equivalent Chemical Indexing
				in CA/CAplus
MEMO	EVD	n m e e	142 V	26 09 CURRENT WINDOWS VERSION IS V8.4,
MEMO	EVEVEDO			CHIPDENT DISCOVED FILE IS DATED 06 ADDIT 2009

NEWS EXPRESS MAY 26 09 CURRENT WINDOWS VERSION IS V8.4, AND CURRENT DISCOVER FILE IS DATED 06 APRIL 2009.

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STRUCTURE FILE UPDATES: 8 JAN 2010 HIGHEST RN 1201769-11-0 DICTIONARY FILE UPDATES: 8 JAN 2010 HIGHEST RN 1201769-11-0

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chain nodes :

ring nodes : 1 2 3 4 5 6 7 8 9 10 11 12 13 14 ring bonds :

1-2 1-6 2-3 3-4 4-5 5-6 5-7 6-10 7-8 8-9 8-11 9-10 9-14 11-12 12-13 13-14 normalized bonds:
1-2 1-6 2-3 3-4 4-5 5-6 5-7 6-10 7-8 8-9 8-11 9-10 9-14 11-12 12-13 13-14

Match level :

1:Atom 2:Atom 3:Atom 4:Atom 5:Atom 6:Atom 7:Atom 8:Atom 9:Atom 10:Atom 11:Atom 12:Atom 13:Atom 14:Atom 15:CLASS 16:Atom

L1 STRUCTURE UPLOADED

=> D L1 L1 HAS NO ANSWERS L1 STR



Structure attributes must be viewed using STN Express query preparation.

=> S L1 FULL FULL SEARCH INITIATED 16:23:00 FILE 'REGISTRY' FULL SCREEN SEARCH COMPLETED - 562821 TO ITERATE

100.0% PROCESSED 562821 ITERATIONS (3 INCOMPLETE) 38662 ANSWERS SEARCH TIME: 00.00.14

L2 38662 SEA SSS FUL L1

=> FILE CAPLUS COST IN U.S. DOLLARS

COST IN U.S. DOLLARS SINCE FILE TOTAL ENTRY SESSION

FULL ESTIMATED COST 193.01 193.23

FILE 'CAPLUS' ENTERED AT 16:24:03 ON 09 JAN 2010
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FILE COVERS 1907 - 9 Jan 2010 VOL 152 ISS 3
FILE LAST UPDATED: 8 Jan 2010 (20100108/ED)
REVISED CLASS FIELDS (/NCL) LAST RELOADED: Oct 2009
USPTO MANUAL OF CLASSIFICATIONS THESAURUS ISSUE DATE: Oct 2009

CAplus now includes complete International Patent Classification (IPC) reclassification data for the third quarter of 2009.

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This file contains CAS Registry Numbers for easy and accurate substance identification.

=> S L2 L3 32086 L2

=> S L3 AND BINDER 211249 BINDER

L4 193 L3 AND BINDER

=> S L4 AND PERMITIVITY
18 PERMITIVITY

L5 0 L4 AND PERMITIVITY

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L6 4 L4 AND SEMICONDUCTING

=> D L6 IBIB ABS HITSTR 1-4

L6 ANSWER 1 OF 4 CAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2009:1589017 CAPLUS

DOCUMENT NUMBER: 152:57976

TITLE: Process for preparing substituted pentacenes

INVENTOR(S): Tierney, Steven; Heeney, Martin; Bailey, Clare; Zhang, Weimin

PATENT ASSIGNEE(S): Merck Patent GmbH, Germany

SOURCE: PCT Int. Appl., 48pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO. KIND DATE APPLICATION NO. DATE

WO 2008128618 A1 20081030 WO 2008-EP2485 20080328

01/09/2010

W: AE, AG, AL, AM, AO, AT, AU, AZ, BA, BB, BG, BH, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DO, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, GT, HN, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KN, KP, KR, KZ, LA, LC, LK, LR, LS, LT, LU, LY, MA, MD, ME, MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, SV, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HR, HU, IE, IS, IT, LT, LU, LV, MC, MT, NL, NO, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM EP 2134725 A1 20091223 EP 2008-716713 20080328 R: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HR, HU, IE, IS, IT, LI, LT, LU, LV, MC, MT, NL, NO, PL, PT, RO, SE, SI, SK, TR

PRIORITY APPLN. INFO .:

EP 2007-7947 A 20070419 WO 2008-EP2485 W 20080328

The invention relates to a process of preparing substituted pentacenes, to novel pentacenes prepared by this process, to the use of the novel pentacenes as semiconductors or charge transport materials in optical, electrooptical or electronic devices including field effect transistors (FETs), electroluminescent, photovoltaic and sensor devices, and to FETs and other semiconducting components or materials comprising the novel pentacenes. Thus, 1,4,8,11-tetramethyl-6,13-

bis(triethylsilylethynyl)dentacene was prepared and used as a semiconductor for an OFET device, showing high mobility and a high on/off ratio.

1173698-76-4P, 1,4,8,11-Tetramethyl-6,13bis(triethylsilylethynyl)dentacene

RL: IMF (Industrial manufacture); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(process for preparing substituted pentacenes d as semiconductors or charge transport materials in optical, electrooptical or electronic devices)

RN 1173698-76-4 CAPLUS

CN Pentacene, 1,4,8,11-tetramethyl-6,13-bis[2-(triethylsilyl)ethynyl]- (CA INDEX NAME)

REFERENCE COUNT:

THERE ARE 1 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

1 ANSWER 2 OF 4 CAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2007:816621 CAPLUS

DOCUMENT NUMBER: 147:224628 TITLE: Electronic short channel device comprising an organic

semiconductor formulation

INVENTOR(S): Ogier, Simon Dominic; Veres, Janos; Zeidan, Munther INVENTOR(S): Ogier, Simon Dominic; Veres, J. PATENT ASSIGNEE(S): Merck Patent G.m.b.H., Germany

SOURCE: PCT Int. Appl., 46pp. CODEN: PIXXD2

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1 PATENT INFORMATION:

	PATENT NO.				KIND DATE			APPLICATION NO.						DATE				
				A1				WO 2006-EP12300										
		W:	ΑE,	AG,	AL,	AM,	AT,	AU,	ΑZ,	BA,	BB,	BG,	BR,	BW,	BY,	ΒZ,	CA,	CH,
			CN,	CO,	CR,	CU,	CZ,	DE,	DK,	DM,	DZ,	EC,	EE,	EG,	ES,	FI,	GB,	GD,
			GE,	GH,	GM,	GT,	HN,	HR,	HU,	ID,	IL,	, IN,	IS,	JP,	KE,	KG,	KM,	KN,
			ΚP,	KR,	ΚZ,	LA,	LC,	LK,	LR,	LS,	LT,	LU,	LV,	LY,	MA,	MD,	MG,	MK,
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						RU,												
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									CN 2006-80051140									
	KR 2008096781					A		2008	1103								0080	
PRIOR	PRIORITY APPLN. INFO.:											2006-					0060	
											WO 2	2006-l	SP12.	300		n 2	0061	220

The invention relates to an improved electronic device, like an organic field emission transistor (OFET), which has a short source to drain channel length and contains an organic semiconducting formulation

comprising a semiconducting binder. IT 373596-08-8

> RL: PRP (Properties); TEM (Technical or engineered material use); USES (Uses)

(electronic short channel device comprising an organic semiconductor formulation in organic field emission transistors)

RN 373596-08-8 CAPLUS

CN Pentacene, 6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

C C Si(Pr-i)3

OS.CITING REF COUNT: 2 THERE ARE 2 CAPLUS RECORDS THAT CITE THIS RECORD

(2 CITINGS)

REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS
RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L6 ANSWER 3 OF 4 CAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2006:437554 CAPLUS

DOCUMENT NUMBER: 144:479184

TITLE: Process for making an organic field effect transistor

with areas of reduced carrier mobility
INVENTOR(S): Brown, Beyerley Anne; Veres, Janos; Ogier, Simon

Dominic

PATENT ASSIGNEE(S): Merck Patent G.m.b.H., Germany SOURCE: PCT Int. Appl. 24 pp.

OURCE: PCT Int. Appl., 24 pp.

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1 PATENT INFORMATION:

KIND DATE APPLICATION NO. DATE PATENT NO. ______ ____ WO 2006048092 A1 20060511 WO 2005-EP10661 20051004 W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, LY, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM EP 1807884 EP 2005-790320 A1 20070718 20051004 EP 1807884 20080702 B1 R: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LI, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR JP 2008519445 20080605 JP 2007-539481 T 20051004 AT 400067 AT 2005-790320 Τ 20080715 20051004 KR 2007-710026 KR 2007083921 A 20070824 20070502 A1 US 20070259477 20071108 US 2007-666751 20070502 PRIORITY APPLN. INFO.: GB 2004-24342 A 20041103 WO 2005-EP10661 W 20051004

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

AB The present invention relates to a process for reducing the mobility of an organic semiconductor (OSC) layer in an electronic device having a semiconducting channel area. The mobility of the OSC is reduced in specific areas outside the channel area by applying an oxidizing agent

to the OSC layer. 373596-08-8

RL: DEV (Device component use); USES (Uses)

(organic semiconductor layer; process for making an organic field effect transistor with areas of reduced carrier mobility)

RM 373596-08-8 CAPLUS

CN Pentacene, 6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

C C Si(Pr-i) 3 C C Si(Pr-i) 3

REFERENCE COUNT: THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD, ALL CITATIONS AVAILABLE IN THE RE FORMAT

L6 ANSWER 4 OF 4 CAPLUS COPYRIGHT 2010 ACS on STN

2005:523782 CAPLUS ACCESSION NUMBER:

DOCUMENT NUMBER: 143:69829

TITLE: Improvements in and relating to organic

semiconducting layers INVENTOR(S):

Brown, Beverley Anne; Veres, Janos; Anemian, Remi Manouk; Williams, Richard Thomas; Ogier, Simon

Dominic; Leeming, Stephen William

PATENT ASSIGNEE(S): Avecia Limited, UK

SOURCE: PCT Int. Appl., 68 pp. CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: English FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO. KIND DATE APPLICATION NO. DATE WO 2005055248 A2 20050616 WO 2004-GB4973 20041125 WO 2005055248 A3 20050728 W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO. NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW, RW: BW, GH, GH, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG

EP	1687	830			A2		2006	0809		EP :	2004-	8197	15		2	0041	125
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		IE,	SI,	FI,	RO,	CY,	TR,	BG,	CZ,	EE	, HU,	PL,	SK,	IS			
EP	1783	781			A2		2007	0509		EP :	2007-	2498			- 2	0041	125
EP	1783	781			A3		2007	1003									
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		IS,	IT,	LI,	LU,	MC,	NL,	PL,	PT,	RO	, SE,	SI,	SK,	TR			
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EP	1808	866			A1		2007	0718		EP :	2007-	4534			2	0041	125
	R:	AT,	BE,	BG,	CH,	CY,	CZ,	DE,	DK,	EE	, ES,	FI,	FR,	GB,	GR,	HU,	ΙE,
		IS,	IT,	LI,	LU,	MC,	NL,	PL,	PT,	RO	, SE,	SI,	SK,	TR			
KR	2006	1103	09		A		2006	1024		KR :	2006-	7103	74		2	0060	526
US	2007	0102	696		A1		2007	0510		US :	2006-	5805	52		- 2	0060	526
											2007-					0070	206
US	2008	0009	625		A1		2008	0110		US :	2007-	8225	94		2	0070	709
US	7576	208			B2		2009	0818									
PRIORIT	Y APP	LN.	INFO	. :						GB :	2003-	2765	4		A 2	0031	128
											2004-						
										GB :	2004-	1434	7		A 2	0040	626
										EP :	2004-	8197	15		A3 2	0041	125
										WO :	2004-	GB49	73		W 2	0041	125
										US :	2006-	5805	52		A3 2	0060	526
ASSIGNM										N L	SUS D	ISPL	AY F	ORMA	Т		

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT OTHER SOURCE(S): MARPAT 143:69829 GI

An organic semiconducting layer formulation (I), which comprises: an organic binder which has a permittivity, &, at 1,000 Hz of 3.3 or less; and a polyacene compound of Formula: A: wherein; each of R1, R2, R3, R4, R5, R6, R7, R8, R9, R10, R11 and R12, which may be the same or different, independently represents hydrogen; an optionally substituted C1-C40 carbyl or hydrocarbyl group; an optionally substituted C1-C40 alkoxy group; an optionally substituted C6-C40 aryloxy group; an optionally substituted C7-C40 alkylaryloxy group; an optionally substituted C2-C40 alkoxycarbonyl group; an optionally substituted C7-C40 aryloxycarbonyl group; a cyano group (-CN); a carbamoyl group (-C(= O)NH2); a haloformyl group (-C(= O)-X, wherein X represents a halogen atom); a formyl group (-C(= 0)-H); an isocyano group; an isocyanate group; a thiocyanate group or a thioisocyanate group; an optionally substituted amino group; a hydroxy group. A nitro group; a CF3 group; a halo group (CI, Br, F); or an optionally substituted silvl group; and wherein independently each pair of R2 and R3 and/or R8 and R9, may be cross-bridged to form a C4-C40 saturated or unsatd. ring, which saturated or unsatd. ring may be intervened by an oxygen atom, a sulfur atom or a group shown by formula -N(Ra)- (wherein Ra is a hydrogen atom or an optionally

substituted hydrocarbon group), or may optionally be substituted; and wherein one or more of the carbon atoms of the polyacene skeleton may optionally be substituted by a heteroatom selected from N, P, As, O, S, Se and Te; and wherein independently any two or more of the substituents R1-R12 which are located on adjacent ring positions of the polyacene may, together, optionally constitute a further C4-C40 saturated or unsatd. ring optionally interrupted by O, S or -N(Ra) where Ra is as defined above or an aromatic ring system, fused to the polyacene; and wherein n is 0, 1, 2, 3 or 4, also claimed is an electronic device, particularly.

IT 317809-68-0 373596-08-8 373596-09-9 398128-81-9 775324-33-9 775324-34-0 854519-90-7 854519-91-8 854519-92-9 854519-96-3 854520-00-6 RL: DEV (Device component use); USES (Uses)

(improvements in and relating to organic semiconducting layers

for organic FETs) RN 317809-68-0 CAPLUS

CN Pentacene, 6,13-bis[2-(trimethylsilyl)ethynyl]- (CA INDEX NAME)

C C SiMe 3

RN 373596-08-8 CAPLUS

CN Pentacene, 6,13-bis[2-[tris(1-methylethyl)silvl]ethynyl]- (CA INDEX NAME)

C== C-Si(Pr-i)3

RN 373596-09-9 CAPLUS

CN Pentacene, 5,14-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

(i-Pr)3Si-C ≡ C

(i-Pr)3Si-C C

- RN 398128-81-9 CAPLUS
- CN Pentacene, 6,13-bis[2-(triethylsilyl)ethynyl]- (CA INDEX NAME)

- 775324-33-9 CAPLUS RN
- Anthra[2,3-b:6,7-b']dithiophene, 5,11-bis[2-[tris(1-CN methylethyl)silyl]ethynyl]- (CA INDEX NAME)

C C Si(Pr-i) 3

- C C Si(Pr-i)3
- 775324-34-0 CAPLUS RN CN Silane, (anthra[2,3-b:7,6-b']dithiophene-5,11-diyldi-2,1ethynediyl)bis[tris(1-methylethyl)- (9CI) (CA INDEX NAME)

- C = C Si (Pr-i) 3
- RN 854519-90-7 CAPLUS
- Pentacene, 2,3,9,10-tetramethyl-6,13-bis[2-[tris(1-CN methylethyl)silyl]ethynyl]- (CA INDEX NAME)

$$\begin{array}{c} C = C - Si(Pr - i) 3 \\ \text{Me} \\ \text{Me} \\ C = C - Si(Pr - i) 3 \end{array}$$

- RN 854519-91-8 CAPLUS
- CN Pentacene, 6,13-bis[2-(4-pentylphenyl)ethynyl]- (CA INDEX NAME)

- RN 854519-92-9 CAPLUS
- CN Dibenzo[1,pqr]benz[a]anthracene, 7,12-bis[2-[tris(1methylethyl)silyl]ethynyl]- (CA INDEX NAME)

- (i-Pr)3Si C = C
- RN 854519-95-2 CAPLUS
- CN Pentacene, 1,8-difluoro-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl](CA INDEX NAME)

STN: SEARCH

RN 854519-96-3 CAPLUS

CN Pentacene, 1,11-difluoro-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]-(CA INDEX NAME)

854520-00-6 CAPLUS RN

CN Pentacene, 2,3,9,10-tetrafluoro-6,13-bis[2-[tris(1methylethyl)silyl]ethynyl]- (CA INDEX NAME)

OS.CITING REF COUNT: 11 THERE ARE 11 CAPLUS RECORDS THAT CITE THIS RECORD (12 CITINGS)

REFERENCE COUNT: 2 THERE ARE 2 CITED REFERENCES AVAILABLE FOR THIS RECORD, ALL CITATIONS AVAILABLE IN THE RE FORMAT

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Executing the logoff script...

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COST IN U.S. DOLLARS	SINCE FILE ENTRY	TOTAL SESSION
FULL ESTIMATED COST	34.17	227.40
DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS)	SINCE FILE ENTRY	TOTAL SESSION
CA SUBSCRIBER PRICE	-3.40	-3.40

STN INTERNATIONAL LOGOFF AT 16:28:35 ON 09 JAN 2010